

256-BIT

MOS Random Access Memory

MOSTEK

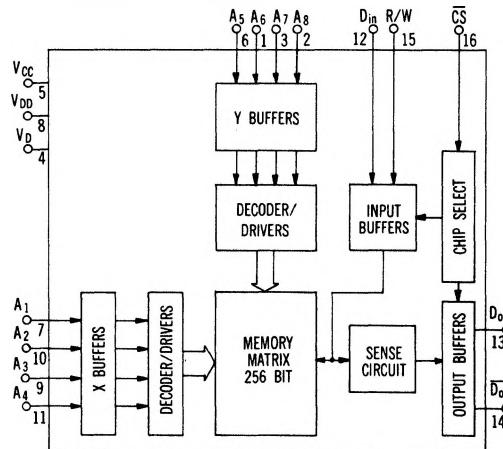
Random
Access
Memories

- Low-cost 256x1 RAM in 16-pin package.
- Identical with Mostek's MK 4007 P in all specifications except output current

DESCRIPTION

This economical version of Mostek's 256x1 bit RAM is identical with the MK 4007 P in all electrical characteristics except output current. Performance, operating conditions, timing characteristics, package, and all other specifications are identical with the MK 4007 P. See the MK 4007 P Data Sheet for additional information.

FUNCTIONAL DIAGRAM



ELECTRICAL CHARACTERISTICS

(Ambient Temperature Range: 0°C to +75°C. $V_{CC} = +5\text{ V} \pm 5\%$; $V_D = V_{DD} = -7\text{ V}$ to -13.2 V , unless otherwise specified.)

	PARAMETER	MIN	TYP	MAX	UNITS	CONDITIONS
POWER	I_D I_{DD} P_D		8.0 4.0 170	16 9 370	mA mA mW	$V_D = V_{DD} = -9\text{ V} \pm 5\%$ Outputs open-circuited.
	I_D I_{DD} P_D			19 10 535	mA mA mW	$V_D = V_{DD} = -13.2\text{ V}$ $V_{CC} = +5.25\text{ V}$ Outputs open-circuited.
	P_{SBY}		30	75	mW	$V_D = V_{CC}; V_{DD} = -9\text{ V} \pm 5\%$
INPUTS	$I_{IL(L)}$			1.0	μA	$V_{IN} = 0\text{ V}, T_A = 25^\circ\text{C}$
	C_{IN} $C_{V(D)}$		7 35	10	pF pF	$T_A = 25^\circ\text{C}$, F. Meas. = 1 MHz; Tested input = V_{CC}
OUTPUTS	I_{OL} I_{OH} I_{OLC}	3.0 2.0 -1.0	5.6 -4.2	8.0	mA mA mA mA	$V_O = +0.40\text{ V}$ $V_{CC} = 5.0\text{ V} \pm 5\%$ $V_O = +0.40\text{ V}$ $V_D = V_{DD} = -9.0\text{ V}$ $V_O = +2.6\text{ V}$ $\pm 10\%$ $V_O = -1.0\text{ V}$
	$I_{O(L)}$			1.0	μA	$V_O = V_{CC} - 5\text{ V}$; $\overline{CS} = \text{Logic 1}$; $T_A = 25^\circ\text{C}$.
	C_{OUT}		7	10	pF	$T_A = 25^\circ\text{C}$; F meas. = 1 MHz; $V_O = V_{CC}$

NOTES:

- (1) Typical values at $V_{CC} = +5\text{ V}$, $V_D = V_{DD} = -9.0\text{ V}^*$, $T_A = 25^\circ\text{C}$.
(*Except Standby Power)